

isc N-Channel MOSFET Transistor

AOI4184

• FEATURES

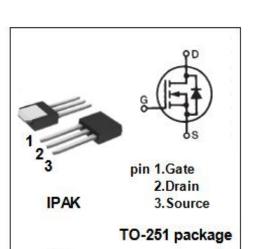
- Drain Current –I_D= 50A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}= 40V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)} = 8m \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

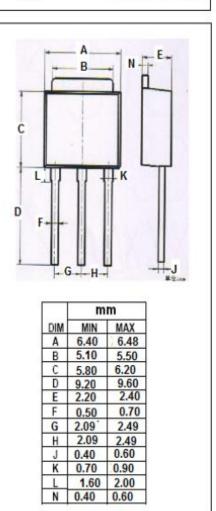
DESCRITION

• Be suitable for synchronous rectification for server and general purpose applications

SYMBOL	PARAMETER VALU		UNIT
V _{DSS}	Drain-Source Voltage 4		V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	50	А
I _{DM}	Drain Current-Single Pulsed	120	A
PD	Total Dissipation @T _c =25°C 50		W
Tj	Max. Operating Junction Temperature -55~175		°C
T _{stg}	Storage Temperature -55~175		°C

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3	°C/W

1



isc N-Channel MOSFET Transistor

AOI4184

ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 250 μ A	40		V
V _{GS} (th)	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D = 250 μ A	1.7	2.6	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 20A V _{GS} = 10V; I _D = 20A;T _J = 125°C		8 13	mΩ
I _{GSS}	Gate-Source Leakage Current	V_{GS} = ±25V; V_{DS} = 0V		±100	nA
Idss	Drain-Source Leakage Current	V _{DS} = 40V; V _{GS} = 0V V _{DS} = 40V; V _{GS} = 0V;T _J = 55°C		1 5	μA
V _{SD}	Diode forward voltage	Is= 1A; V _{GS} = 0V		1	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.